

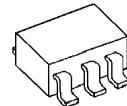
## LOW DROPOUT VOLTAGE REGULATOR

### ■ GENERAL DESCRIPTION

The NJM2870 is low dropout voltage regulator designed for cellular phone application.

Advanced Bipolar technology achieves low noise, high ripple rejection and low quiescent current.

### ■ PACKAGE OUTLINE

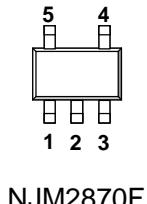


NJM2870F

### ■ FEATURES

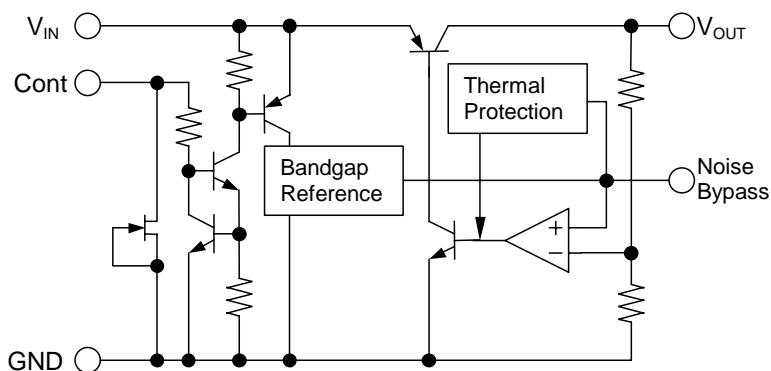
- High Ripple Rejection       $56\text{dB} \leq RR$  ( $\text{DC} < f < 60\text{kHz}$ )  
66dB typ. ( $f=100\text{Hz}$ )  
60dB typ. ( $f=1\text{kHz}$ )
- Output Noise Voltage       $V_{\text{no}}=30\mu\text{V}$  typ. ( $C_p=0.01\mu\text{F}$ )
- Output Current       $I_o(\text{max.})=150\text{mA}$
- High Precision Output       $V_o \pm 2\%$
- Low Dropout Voltage       $\Delta V_{\text{DO}}=0.12\text{V}$  typ. ( $I_o=60\text{mA}$ ,  $V_o \geq 1.8\text{V}$ )
- Input Voltage range      +2~+14V ( $V_o=1.5\text{V}$  Version)
- ON/OFF Control      (Active High)
- Output capacitor with 4.7uF ceramic capacitor
- Internal Short Circuit Current Limit
- Internal Thermal Overload Protection
- Bipolar Technology
- Package Outline      SOT-23-5

### ■ PIN CONFIGURATION



- PIN FUNCTION**
1. CONTROL (Active High)
  2. GND
  3. NOISE BYPASS
  4.  $V_{\text{OUT}}$
  5.  $V_{\text{IN}}$

### ■ EQUIVALENT CIRCUIT



## ■ ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

PARAMETER	SYMBOL	RATINGS		UNIT
Input Voltage	V <sub>IN</sub>	+14		V
Control Voltage	V <sub>CONT</sub>	+14(*1)		V
Power Dissipation	P <sub>D</sub>	SOT-23-5	350(*2) 200(*3)	mW
Operating Temperature	Topr	-40 ~ +85		°C
Storage Temperature	Tstg	-40 ~ +125		°C

(\*1) When input voltage is less than +14V, the absolute maximum control voltage is equal to the input voltage.

(\*2): Mounted on glass epoxy board based on EIA/JEDEC. (114.3x76.2x1.6mm: 2Layers)

(\*3): Device itself.

■ ELECTRICAL CHARACTERISTICS (V<sub>IN</sub>=Vo+1V, C<sub>IN</sub>=0.1μF, Co=4.7μF, Cp=0.01μF, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo	I <sub>O</sub> =30mA	-2%	—	+2%	V
Quiescent Current	I <sub>Q</sub>	I <sub>O</sub> =0mA, expect I <sub>cont</sub>	—	200	300	μA
Quiescent Current at Control OFF	I <sub>Q(OFF)</sub>	V <sub>CONT</sub> =0V	—	—	100	nA
Output Current	I <sub>O</sub>	Vo-0.3V	150	200	—	mA
Line Regulation	ΔVo/ΔV <sub>IN</sub>	V <sub>IN</sub> =Vo+1V ~ Vo+6V, I <sub>O</sub> =30mA	—	—	0.10	%/V
Load Regulation	ΔVo/ΔI <sub>O</sub>	I <sub>O</sub> =0 ~ 100mA	—	—	0.03	%/mA
Dropout Voltage	ΔV <sub>I-O</sub>	I <sub>O</sub> =60mA	—	0.12	0.2	V
Ripple Rejection	RR	ein=200mVrms, f=1kHz, I <sub>O</sub> =10mA V <sub>IN</sub> =Vo+2V, Vo=3V Version	—	60	—	dB
Average Temperature Coefficient of Output Voltage	ΔVo/ΔTa	Ta=0~85°C, I <sub>O</sub> =10mA, Vo=3V Version	—	0.2	—	mV/°C
Output Noise Voltage	V <sub>NO</sub>	f=10Hz~80kHz, I <sub>O</sub> =10mA, Vo=3V Version	—	30	—	μVrms
Control Voltage for ON-state	V <sub>CONT(ON)</sub>		1.6	—	—	V
Control Voltage for OFF-state	V <sub>CONT(OFF)</sub>		—	—	0.6	V

The above specification is a common specification for all output voltages.

Therefore, it may be different from the individual specification for a specific output voltage.

## ■ ELECTRICAL CHARACTERISTICS

(Vo=1.5V Version, V<sub>IN</sub>=2.4V, C<sub>IN</sub>=0.1μF, Co=4.7μF, Cp=0.01μF, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Voltage	Vo	I <sub>O</sub> =30mA	-2%	—	+2%	V
Quiescent Current	I <sub>Q</sub>	I <sub>O</sub> =0mA, expect I <sub>cont</sub>	—	200	300	μA
Quiescent Current at Control OFF	I <sub>Q(OFF)</sub>	V <sub>CONT</sub> =0V	—	—	100	nA
Output Current	I <sub>O</sub>	Vo-0.3V	150	200	—	mA
Line Regulation	ΔVo/ΔV <sub>IN</sub>	V <sub>IN</sub> =Vo+1V ~ Vo+6V, I <sub>O</sub> =30mA	—	—	0.10	%/V
Load Regulation	ΔVo/ΔI <sub>O</sub>	I <sub>O</sub> =0 ~ 100mA	—	—	0.03	%/mA
Ripple Rejection	RR	ein=200mVrms, f=1kHz, I <sub>O</sub> =10mA V <sub>IN</sub> =Vo+2V	—	64	—	dB
Average Temperature Coefficient of Output Voltage	ΔVo/ΔTa	Ta=0~85°C, I <sub>O</sub> =10mA	—	0.13	—	mV/°C
Output Noise Voltage	V <sub>NO</sub>	f=10Hz~80kHz, I <sub>O</sub> =10mA,	—	15	—	μVrms
Control Voltage for ON-state	V <sub>CONT(ON)</sub>		1.6	—	—	V
Control Voltage for OFF-state	V <sub>CONT(OFF)</sub>		—	—	0.6	V

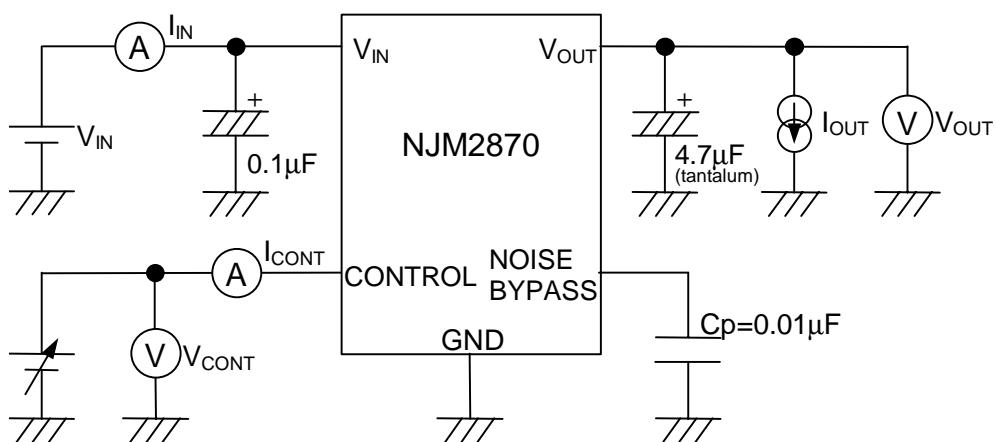
## ■ OUTPUT VOLTAGE RANK LIST

Device Name	$V_{OUT}$
NJM2870F15	1.5V
NJM2870F18	1.8V
NJM2870F19	1.9V
NJM2870F02	2.0V
NJM2870F21	2.1V
NJM2870F23	2.3V
NJM2870F24	2.4V
NJM2870F25	2.5V
NJM2870F26	2.6V

Device Name	$V_{OUT}$
NJM2870F27	2.7V
NJM2870F28	2.8V
NJM2870F285	2.85V
NJM2870F29	2.9V
NJM2870F03	3.0V
NJM2870F31	3.1V
NJM2870F32	3.2V
NJM2870F33	3.3V
NJM2870F34	3.4V

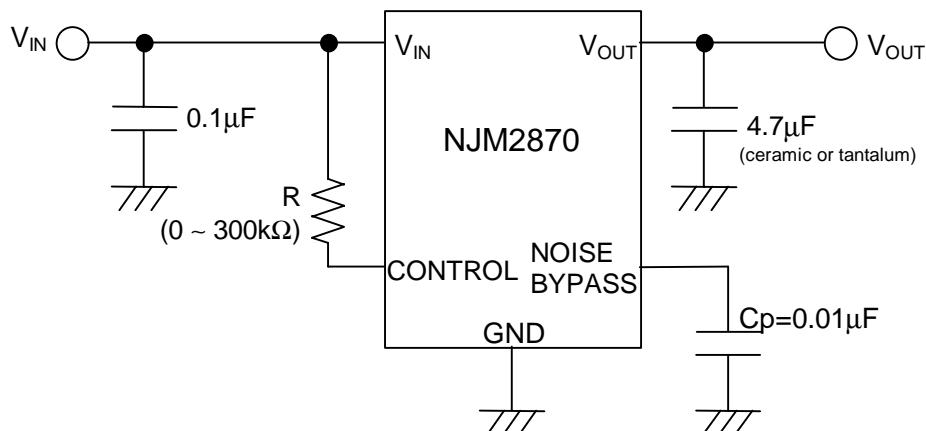
Device Name	$V_{OUT}$
NJM2870F35	3.5V
NJM2870F36	3.6V
NJM2870F38	3.8V
NJM2870F04	4.0V
NJM2870F45	4.5V
NJM2870F46	4.6V
NJM2870F47	4.7V
NJM2870F48	4.8V
NJM2870F05	5.0V

## ■ TEST CIRCUIT



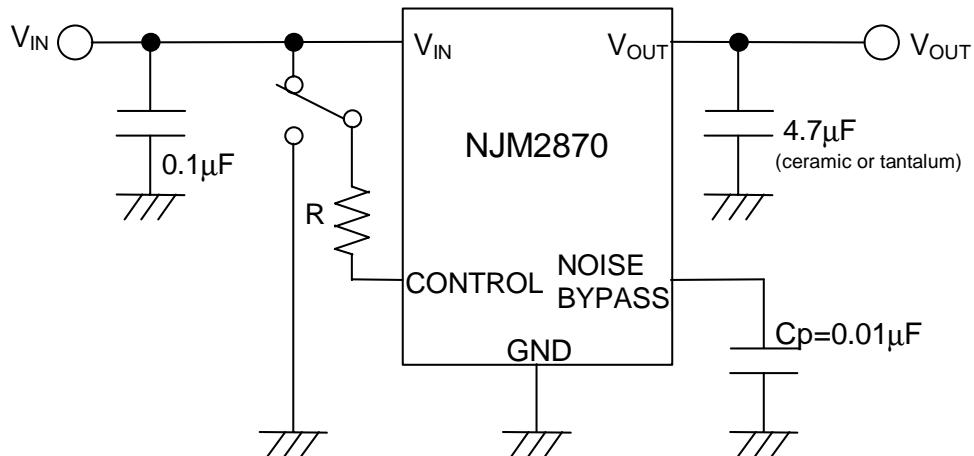
## ■ TYPICAL APPLICATION

- ① In case that ON/OFF Control is not required:



Connect control terminal to  $V_{IN}$  terminal

- ② In use of ON/OFF CONTROL:



State of control terminal:

- “H” → output is enabled.
- “L” or “open” → output is disabled.

### \*Noise bypass Capacitance $C_p$

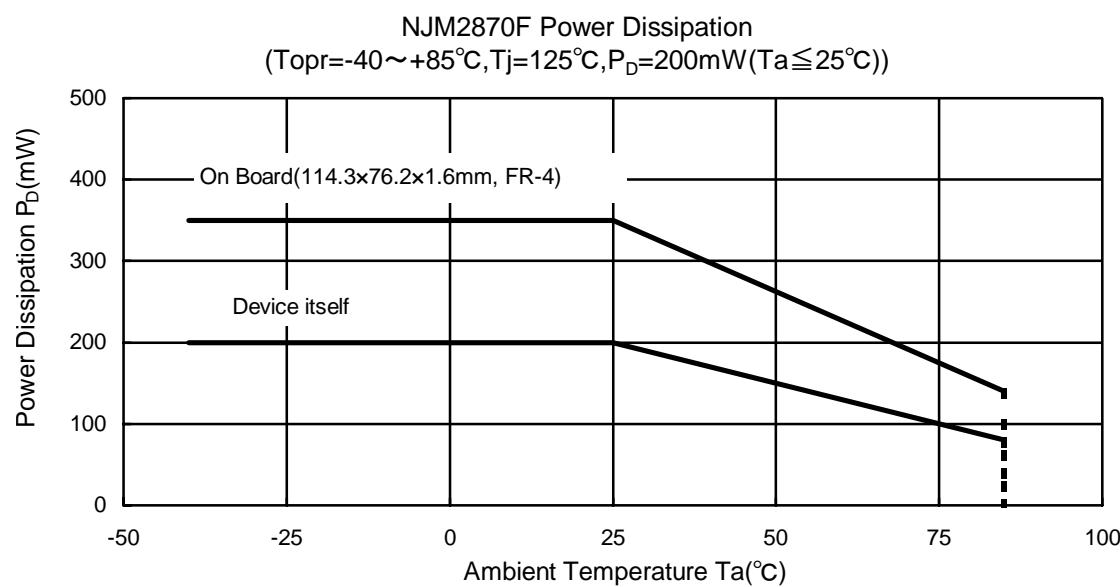
Noise bypass capacitance  $C_p$  reduces noise generated by band-gap reference circuit. Noise level and ripple rejection will be improved when larger  $C_p$  is used. Use of smaller  $C_p$  value may cause oscillation. Use the  $C_p$  value of  $0.01\mu F$  greater to avoid the problem.

### \*In the case of using a resistance "R" between $V_{IN}$ and control.

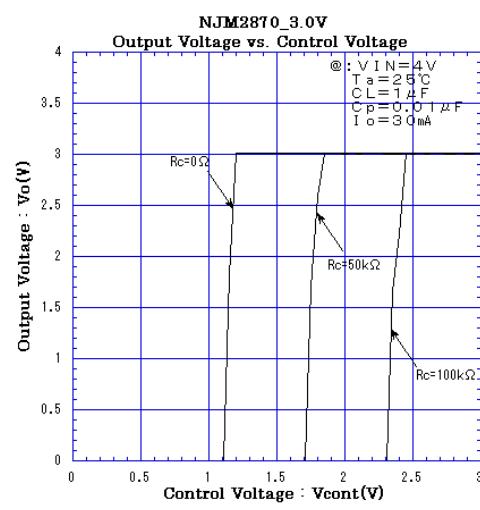
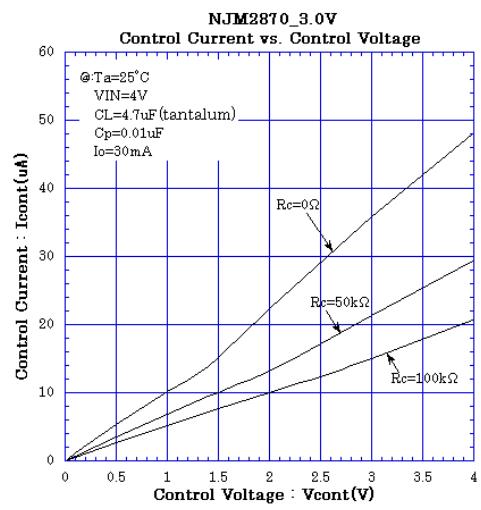
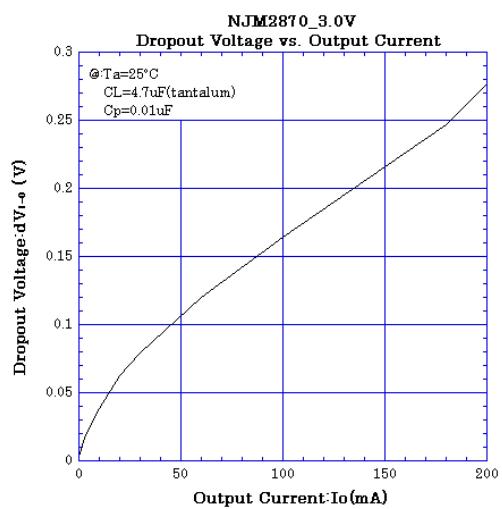
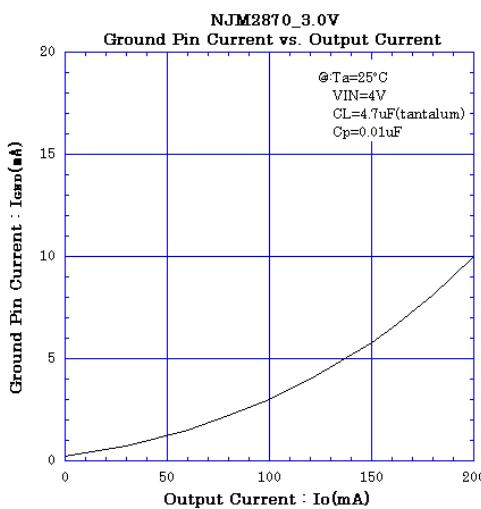
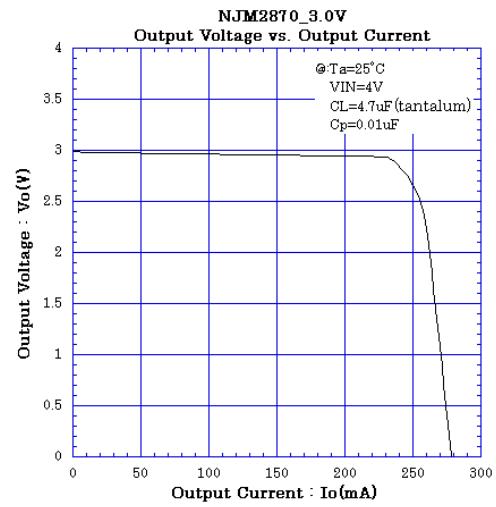
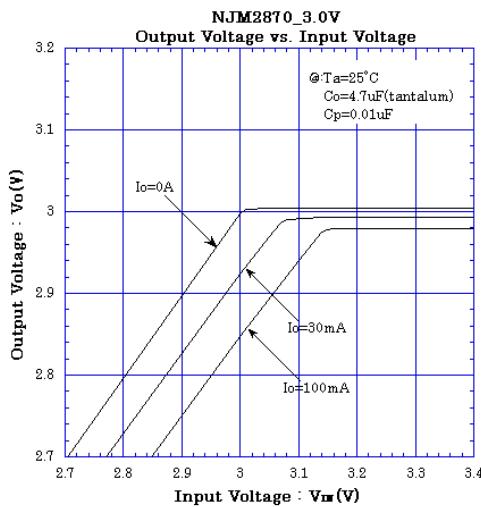
The current flow into the control terminal while the IC is ON state ( $I_{CONT}$ ) can be reduced when a pull up resistance "R" is inserted between  $V_{IN}$  and the control terminal.

The minimum control voltage for ON state ( $V_{CONT(ON)}$ ) is increased due to the voltage drop caused by  $I_{CONT}$  and the resistance "R". The  $I_{CONT}$  is temperature dependence as shown in the "Control Current vs. Temperature" characteristics. Therefore, the resistance "R" should be carefully selected to ensure the control voltage exceeds the  $V_{CONT(ON)}$  over the required temperature range.

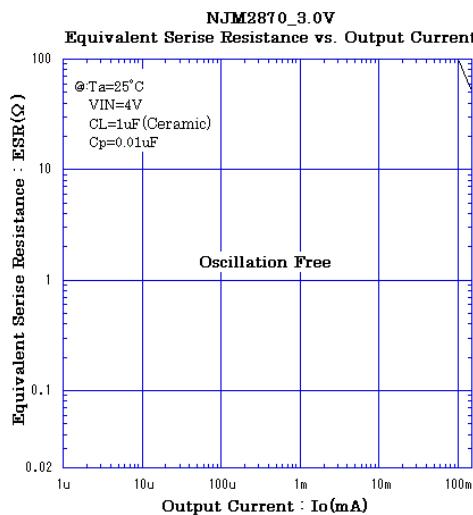
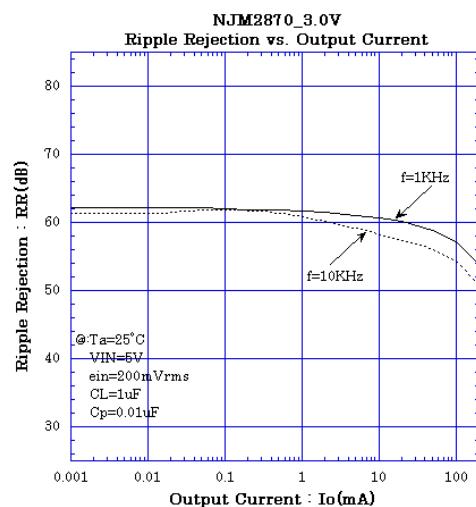
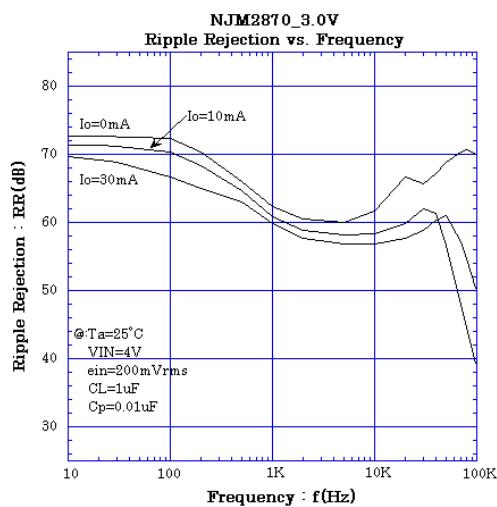
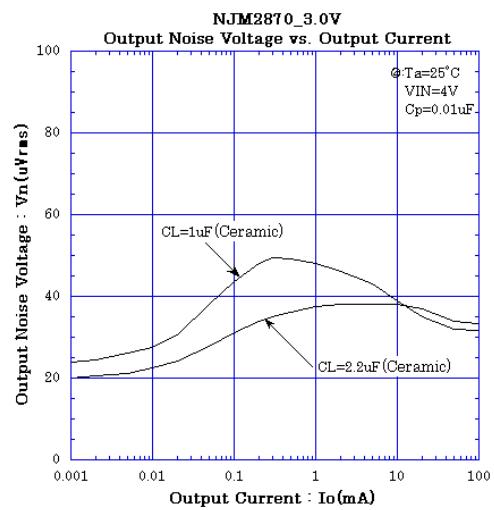
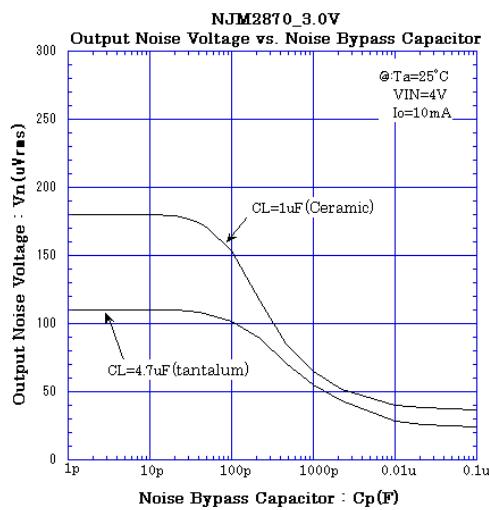
## ■ POWER DISSIPATION vs. AMBIENT TEMPERATURE



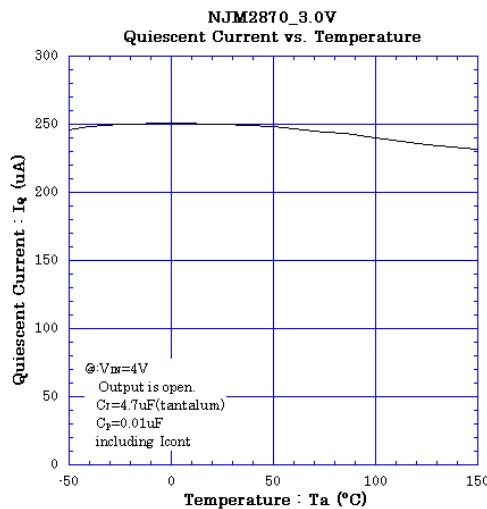
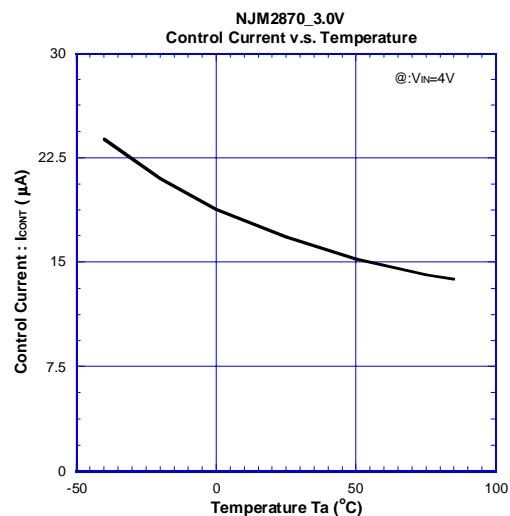
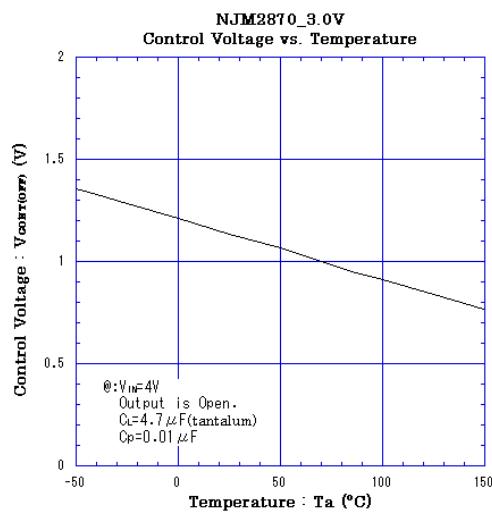
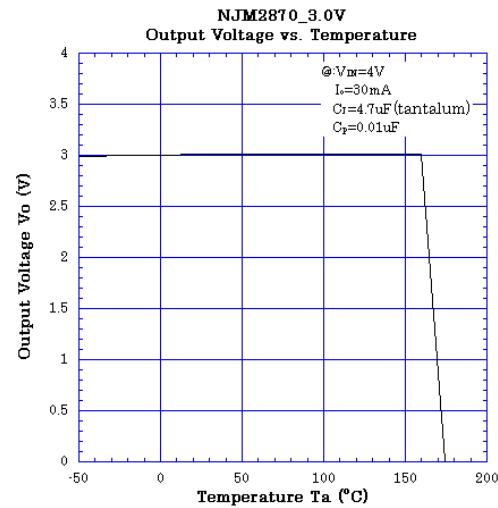
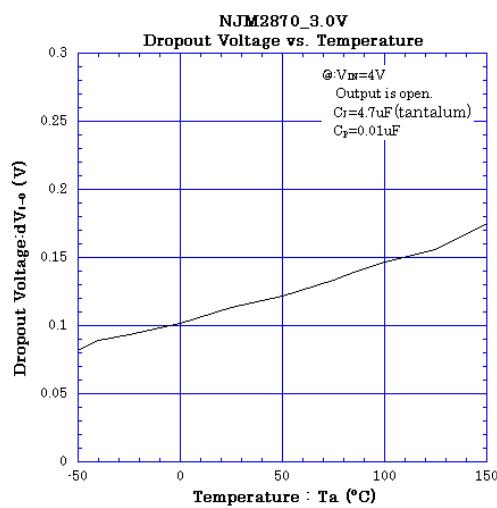
## ■ TYPICAL CHARACTERISTICS



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